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Vishay Semiconductors

HALOGEN

FREE

Small Signal Switching Diodes, High Voltage



FEATURES

- Silicon epitaxial planar diodes
- · Saving space
- · Hermetic sealed parts
- Fits onto SOD-323/SOT-23 footprints
- Electrical data identical with the devices BAV100 to BAV103, BAV200 to BAV203
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



• General purposes





MECHANICAL DATA

Case: MicroMELF
Weight: approx. 12 mg
Cathode band color: black
Packaging codes / options:

TR3/10K per 13" reel (8 mm tape), 10K/box TR/2.5K per 7" reel (8 mm tape), 12.5K/box

| PARTS TABLE | | | | | | |
|-------------|--------------------------|-------------------------|-----------------------|---------------|--|--|
| PART | TYPE DIFFERENTIATION | ORDERING CODE | CIRCUIT CONFIGURATION | REMARKS | | |
| BAV300 | $V_{RRM} = 60 \text{ V}$ | BAV300-TR3 or BAV300-TR | Single | Tape and reel | | |
| BAV301 | V _{RRM} = 120 V | BAV301-TR3 or BAV301-TR | Single | Tape and reel | | |
| BAV302 | V _{RRM} = 200 V | BAV302-TR3 or BAV302-TR | Single | Tape and reel | | |
| BAV303 | V _{RRM} = 250 V | BAV303-TR3 or BAV303-TR | Single | Tape and reel | | |

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|--|--|--------|------------------|-------|------|--|
| PARAMETER | TEST CONDITION | PART | SYMBOL | VALUE | UNIT | |
| | | BAV300 | V_{RRM} | 60 | V | |
| Popotitivo poek roverso voltago | | BAV301 | V_{RRM} | 120 | V | |
| Repetitive peak reverse voltage | | BAV302 | V_{RRM} | 200 | V | |
| | | BAV303 | V_{RRM} | 250 | V | |
| | | BAV300 | V_R | 50 | V | |
| Povorce voltage | | BAV301 | V_R | 100 | V | |
| Reverse voltage | | BAV302 | V _R | 150 | V | |
| | | BAV303 | V_R | 200 | V | |
| Forward continuous current | | | I _F | 250 | mA | |
| Peak forward surge current | t _p = 1 s, T _j = 25 °C | | I _{FSM} | 1 | Α | |
| Forward peak current | f = 50 Hz | | I _{FM} | 625 | mA | |



BAV300, BAV301, BAV302, BAV303

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| THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | |
|---|--|-------------------|-------------|------|--|--|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | | | |
| Thermal resistance junction to ambient air | Mounted on epoxy-glass hard tissue, fig. 4 35 µm copper clad, 0.9 mm ² copper area per electrode | R _{thJA} | 500 | K/W | | | |
| Junction temperature | | Tj | 175 | °C | | | |
| Storage temperature range | | T _{stg} | -65 to +175 | °C | | | |

| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|---------------------------------|--|--------|-------------------|------|------|------|------|
| Forward voltage | I _F = 100 mA | | V_{F} | | | 1 | V |
| | V _R = 50 V | BAV300 | I _R | | | 100 | nA |
| | V _R = 100 V | BAV301 | I _R | | | 100 | nA |
| | V _R = 150 V | BAV302 | I _R | | | 100 | nA |
| Develope accurant | V _R = 200 V | BAV303 | I _R | | | 100 | nA |
| Reverse current | T _j = 100 °C, V _R = 50 V | BAV300 | I _R | | | 15 | μA |
| | T _j = 100 °C, V _R = 100 V | BAV301 | I _R | | | 15 | μA |
| | T _j = 100 °C, V _R = 150 V | BAV302 | I _R | | | 15 | μA |
| | T _j = 100 °C, V _R = 200 V | BAV303 | I _R | | | 15 | μA |
| | $I_R = 100 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$ | BAV300 | V _(BR) | 60 | | | V |
| Develope a allow | | BAV301 | V _(BR) | 120 | | | V |
| Breakdown voltage | | BAV302 | V _(BR) | 200 | | | V |
| | | BAV303 | V _(BR) | 250 | | | V |
| Diode capacitance | V _R = 0 V, f = 1 MHz | | C _D | | 1.5 | | pF |
| Differential forward resistance | I _F = 10 mA | | r _f | | 5 | | Ω |
| Reverse recovery time | $I_F = I_R = 30$ mA, $i_R = 3$ mA, $R_L = 100 \Omega$ | | t _{rr} | | | 50 | ns |

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

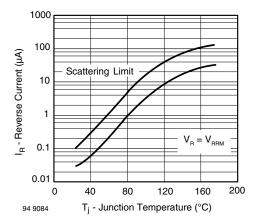


Fig. 1 - Reverse Current vs. Junction Temperature

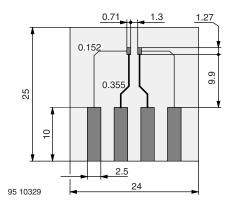


Fig. 4 - Board for R_{thJA} Definition (in mm)

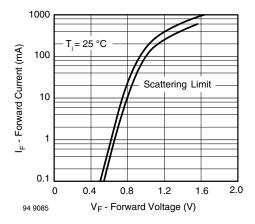


Fig. 2 - Forward Current vs. Forward Voltage

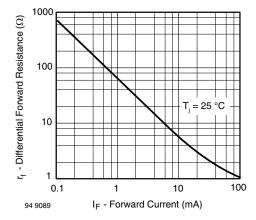


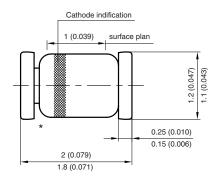
Fig. 3 - Differential Forward Resistance vs. Forward Current

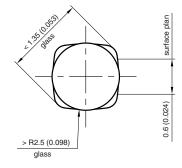


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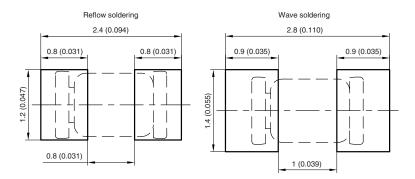
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PACKAGE DIMENSIONS in millimeters (inches): MicroMELF





Foot print recommendation:



Created - Date: 26.July.1996 Rev. 13 - Date: 07.June.2006 Document no.:6.560-5007.01-4 96 12072

^{*} The gap between plug and glass can be either on cathode or anode side



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